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(54) **DISPLAY DEVICE AND A METHOD OF MANUFACTURING THE SAME**

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(58) **Field of Classification Search** ..... 438/35, 438/FOR. 341; 257/89, E51.022, E33.014, 257/E27.117, E25.02

See application file for complete search history.

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(57) **ABSTRACT**

In a display device having a plurality of organic electroluminescence devices arranged on a substrate, each of the devices including a lower electrode, an organic layer at least containing a light emitting layer, and an upper electrode in this order, the light emitting layer of at least some of the organic electroluminescence devices has a first light emitting layer formed by vapor deposition and a second light emitting layer formed by thermal transfer, and the first light emitting layer emits light whose wavelength is equal to or shorter than that of blue light.

**12 Claims, 3 Drawing Sheets**

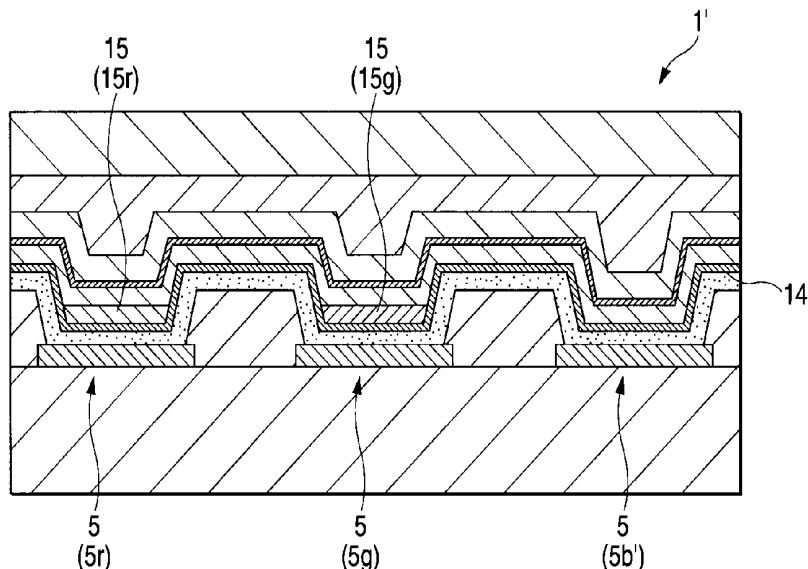


FIG. 1

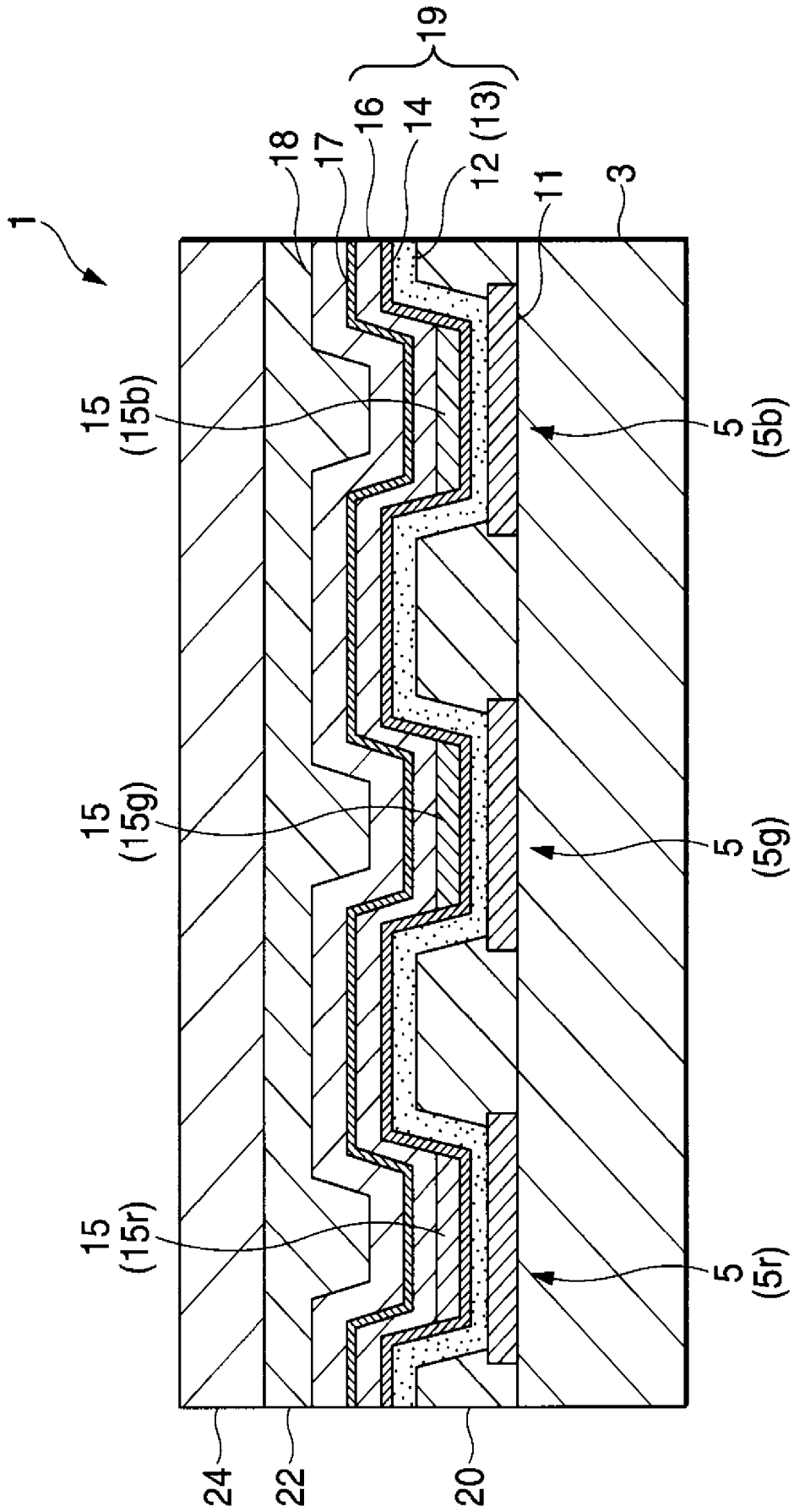


Fig.2

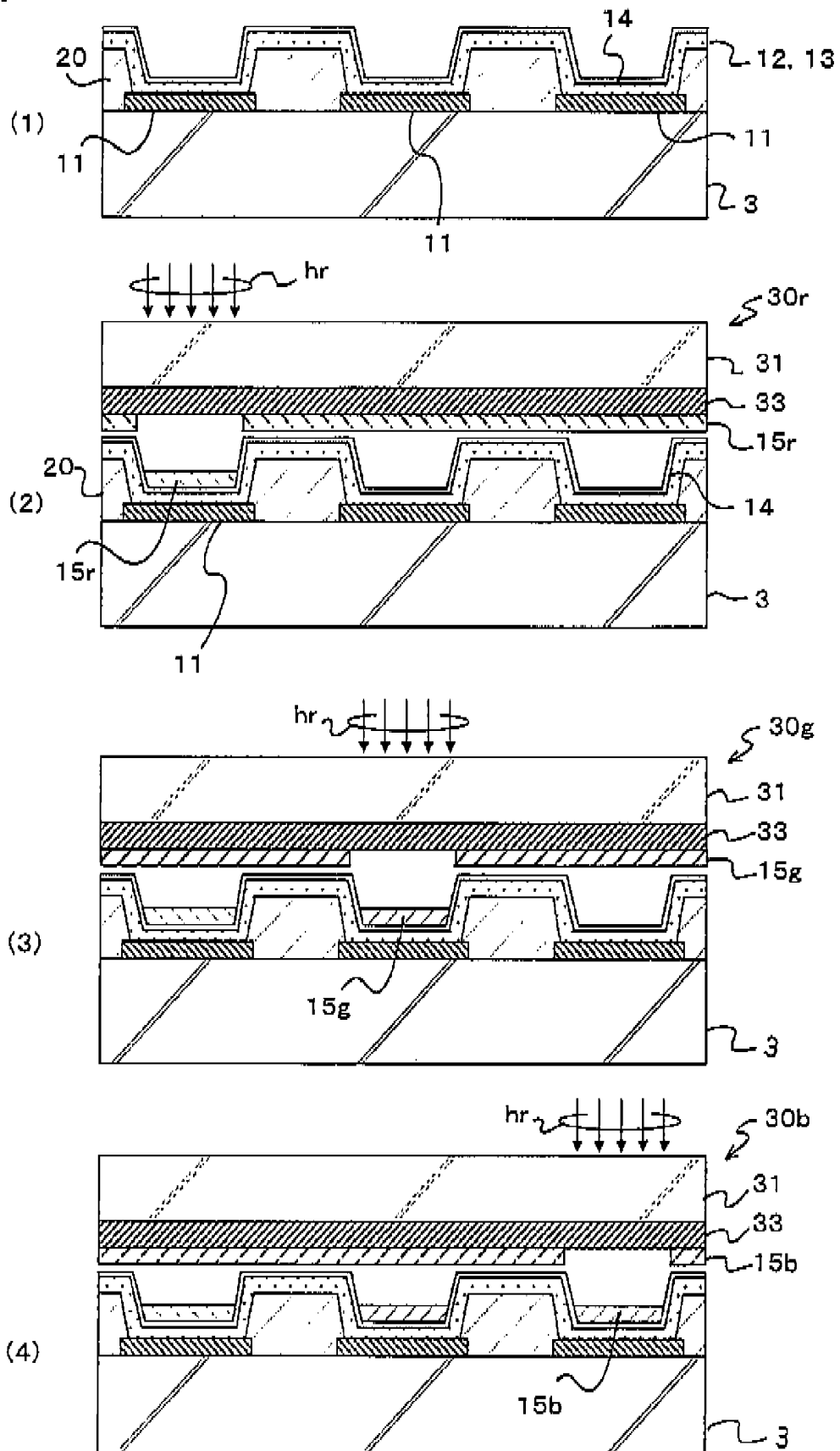
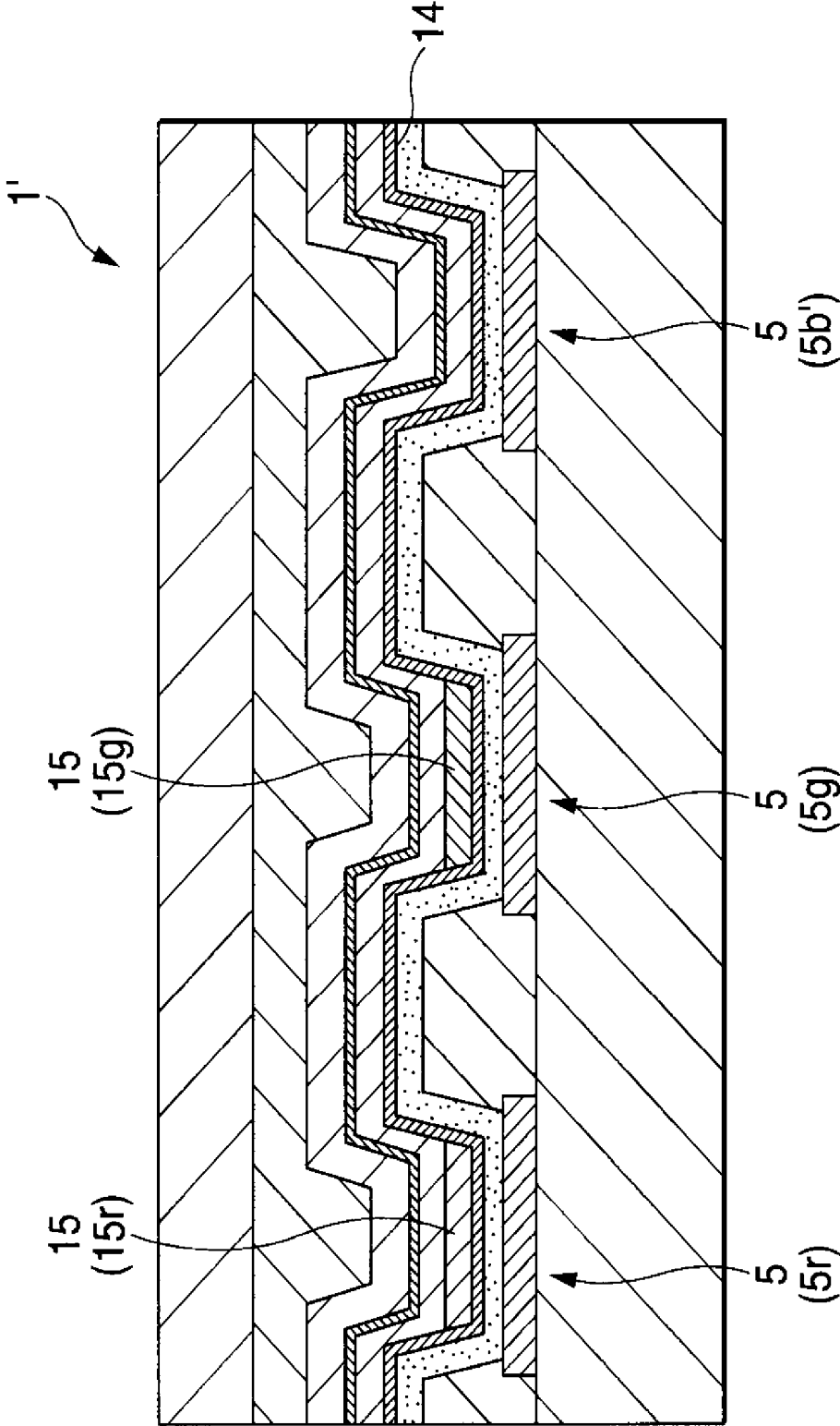


FIG. 3



# DISPLAY DEVICE AND A METHOD OF MANUFACTURING THE SAME

## CROSS REFERENCE TO RELATED APPLICATIONS

The present invention contains subject matter related to Japanese Patent Application JP 2005-119156 filed in the Japanese Patent Office on Apr. 18, 2005, the entire contents of which being incorporated herein by reference.

## BACKGROUND OF THE INVENTION

### 1. Field of the Invention

The present invention concerns a display device and a manufacturing method thereof and, more specifically, it relates to a display device capable of color display using an organic electroluminescence device and a manufacturing method thereof.

### 2. Description of the Related Art

In organic electroluminescence devices, organic layers such as a hole transporting layer and a light emitting layer are provided between a lower electrode and an upper electrode.

In full color display devices using the organic electroluminescence devices (hereinafter simply referred to as light emitting device), light emitting devices that emit respectively R (red), G (green), or B (blue) are arranged on a substrate. In manufacturing such devices, it is necessary to provide a light emitting layer comprising an organic light emitting material that emits each color for each light emitting device. Each light emitting layer is provided, for example, by a shadow masking method in which a light emitting material is deposited or coated through a mask provided with a plurality of apertures, or by an ink jet method.

However, it is difficult to further refine or highly integrate the light emitting devices when using the shadow masking method because of the difficulty of refinement of the apertures of the mask due to the distortion of the mask, etc.

Further, patterning with high accuracy is difficult also in the ink jet method.

Then, as a new pattern forming method, a transfer method using an energy source (heat source) (that is, thermal transfer method) has been proposed. A display device is manufactured by the thermal transfer method, for example, as described below. At first, a lower electrode is formed on a substrate of a display device (hereinafter referred to as a device substrate). On the other hand, a light emitting layer is formed by way of a light absorption layer on another substrate (hereinafter referred to as a transfer substrate). Then, the device substrate and the transfer substrate are placed in a state of opposing the light emitting layer and the lower electrode and a laser light is irradiated on the side of the transfer substrate thereby thermally transferring the light emitting layer on the lower electrode of the device substrate. In this case, by scanning a laser irradiated spotwise, the light emitting layer is thermally transferred with a good positional accuracy only to a predetermined region on the lower electrode (refer to JP-A No. 2002-110350).

## SUMMARY OF THE INVENTION

However, the light emission device obtained by using the thermal transfer method described above has relatively lower light emission efficiency and shorter luminance life compared with the light emission device manufactured by the shadow masking method. This problem is serious particularly in a blue light emitting organic electroluminescence device which

has the shortest luminance life among R (red), G (green), and B (blue) light emitting devices.

In view of the above, there is provided a display device using organic electroluminescence devices capable of patterning each of light emitting layers with good positional accuracy, and capable of maintaining high light emission efficiency and luminance life thereby enabling further fine display.

According to a preferred embodiment of the invention, a display device having a plurality of organic electroluminescence devices arranged on a substrate, each of the devices including a lower electrode, an organic layer at least containing a light emitting layer, and an upper electrode in this order, the light emitting layer of at least some of the organic electroluminescence devices has a first light emitting layer formed by vapor deposition and a second light emitting layer formed by thermal transfer, and the first light emitting layer emits light whose wavelength is equal to or shorter than that of blue light.

According to the preferred embodiment of the invention, each of the light emitting layers can be patterned with good positional accuracy by the thermal transfer method, and high light emission efficiency and long luminance life of the organic electroluminescence device can be obtained. Particularly, the life and the emission efficiency of the blue light emitting device which hindered longer life and higher light emission efficiency can be improved. As a result, further refinement is possible for the color display device in which the organic electroluminescence devices are arranged on the substrate.

## BRIEF DESCRIPTION OF THE DRAWINGS

FIG. 1 is a cross sectional view showing the structure of a display device in accordance with a first embodiment;

FIG. 2 is a cross sectional step charts showing a method of manufacturing a display device of the first embodiment; and

FIG. 3 is a cross sectional view showing the structure of a display device in accordance with a second embodiment.

## DESCRIPTION OF THE PREFERRED EMBODIMENTS

Preferred embodiments of the invention are to be described with reference to the drawings.

### First Embodiment

FIG. 1 is a cross sectional view for main portion of a display device of a preferred embodiment as an example according to the invention. A display device 1 shown in the drawing is a flat panel display of full color indication in which a plurality of organic electroluminescence devices 5 (5r, 5g, and 5b) that emit respectively red (R), green (G), or blue (B) light are arranged above a substrate 3. Hereinafter, an organic electroluminescence device 5 that emits a red light is referred to as a red light emitting device 5r, an organic electroluminescence device 5 that emits a green light is referred to as a green light emitting device 5g, and an organic electroluminescence device 5 that emits a blue light is referred to as the blue light emitting device 5b.

In each of the organic electroluminescence devices 5 (5r, 5g, and 5b), patterned lower electrode 11, hole injecting layer 12, hole transporting layer 13, first light emitting layer 14, second light emitting layers 15 (15r, 15g, 15b), an electron transporting layer 16, an electron injecting layer 17, and an upper electrode 18 are laminated from the side of the substrate

3. In the drawing, the hole injecting layer **12** and the hole transporting layer **13** are shown as one identical layer.

In the organic electroluminescence device **5**, an organic layer **19** consisting of organic materials includes layers from the hole injecting layer **12** to the electron transporting layer **16** for example. Further, the organic electroluminescence devices **5** are separated from each other by an insulating film **20** formed between the lower electrodes **11**.

In this embodiment the light emitting layer of the organic electroluminescence device **5** has a first light emitting layer **14** provided to cover substantially the whole area of the substrate **3** and a second light emitting layers **15** (**15r**, **15g**, and **15b**) provided respectively on each of the organic electroluminescence devices **5** (**5r**, **5g**, and **5b**).

The detailed structure of the display device **1** is to be described at first for the substrate **3**, the lower electrode **11**, and the upper electrode **18** and then the constitution of the organic layer **19** is to be described.

The substrate **3** includes, for example, a glass, silicon or plastic substrate and, further, a TFT substrate formed with TFT (Thin Film Transistor). Particularly when the light emission is taken out from the side of the substrate **3**, the substrate **3** is made of a light transmitting material.

The lower electrode **11** provided on the substrate **3** is used as an anode or a cathode. In such a device as described above, the lower electrode **11** is typically the anode.

The lower electrode **11** is suitably patterned for the driving system of the display device **1**. For example, when the driving system of the display device **1** is a simple matrix type, the lower electrode **11** is formed in stripes for example. Further, when the driving system of the display device **1** is an active matrix type having TFT on every pixel, the lower electrode **11** is formed by patterning so that each electrode corresponds to each of the pixels arranged. The lower electrode **11** is connected to TFT via a contact hole (not illustrated) formed in an interlayer insulating film that covers the TFT.

An insulating film **20** is provided to cover the peripheral portion of the lower electrodes **11**. The insulating film **20** comprises, for example, an organic insulating material such as polyimide or photoresist, or an inorganic insulating material such as silicon oxide.

On the other hand, the upper electrode **18** provided above the lower electrode **11** is used as a cathode. When the lower electrode **11** is used as a cathode, the upper electrode is used as an anode.

When a display device **1** is a simple matrix type one, the upper electrode **18** is formed in stripes to cross the stripes of the lower electrode **11**. Crossed portions of the lower electrode **11** and the upper electrode **18** constitute organic electroluminescence devices **5**. Further, when the display device **1** is an active matrix type one, the upper electrode **18** is formed to cover substantially entire area of the substrate **3** and used as a common electrode for the pixels. For the display device **1** of active matrix type, a top emission type in which the light is taken out from the upper electrode **18** side is preferred because of high aperture of the organic electroluminescence device **5**. In such a case, an auxiliary electrode (not illustrated) can be provided on the same level of the lower electrode **11** to prevent the voltage drop of the upper electrode **18**.

As the anode material for the lower electrode **11** (or upper electrode **18**), materials with high work function and high reflectance are preferred and they include, for example, nickel (Ni), silver (Ag), gold (Au), platinum (Pt), palladium (Pd), selenium (Se), rhodium (Rh), ruthenium (Ru), iridium (Ir), rhenium (Re), tungsten (W), molybdenum (Mo), chromium (Cr), tantalum (Ta), niobium (Nb), aluminum (Al), iron (Fe),

cobalt (Co), copper (Cu), and alloys and oxides thereof, or tin oxide, ITO, zinc oxide, titanium oxide, etc.

On the other hand, as the cathode material for the upper electrode **18** (or lower electrode **11**), materials with low work function are preferred and they include, magnesium (Mg), calcium (Ca), indium (In), lithium (Li), aluminum (Al), silver (Ag) or alloys, oxides or fluorides thereof and, for example, magnesium (Mg)-silver (Ag) alloy, lithium (Li)-fluorine (F) compound, lithium (Li)-oxygen (O) compound, etc.

For the electrode on the side of taking out light emission generated in the organic electroluminescence device **5**, light transmitting materials are used among the materials described above.

For example, when the light emission is taken from the substrate **3** side, the lower electrode **11** is made of the material with high light transmittance such as ITO (Indium-Tin-Oxide) or IZO (Indium-Zinc-Oxide) and used for as the anode. And, the upper electrode **18** is made of the material with good reflectance such as aluminum.

On the other hand, when the light emission is taken from the upper electrode **18** side, the lower electrode **11** is made of the material such as chromium or silver alloy. And, the upper electrode **18** is made of the material with light transmittance such as an alloy of magnesium and silver (MgAg).

In the mean time, it is preferable that the organic electroluminescence device **5** constitutes a resonator structure in which the intensity of the light emission is increased. In this case, the upper electrode **18** is provided as a semi-transparent layer.

The structure of the organic layer **19** is to be described.

At first, the hole injecting layer **12** on the lower electrode **11** is provided as a common layer covering substantially whole area of the substrate **3**. The hole injecting layer **12** comprising a usual hole injecting material, for example m-MTDATA [4,4,4-tris(3-methylphenyl phenylamino)triphenylamine], is vapor deposited with the thickness of 25 nm.

The hole transporting layer **13** is provided on the hole injecting layer **12** as a common layer covering substantially whole area of the substrate **3**. The hole transporting layer **13** comprising a usual hole transporting material, for example  $\alpha$ -NPD [4,4-bis(N-1-naphthyl-N-phenylamino) biphenyl], is vapor deposited with the thickness of 30 nm. Other materials for the hole transporting layer **13** include benzidine derivatives, styrylamino derivatives, triphenylmethane derivatives, hydrazone derivatives, etc.

Each of the hole injecting layer **12** and the hole transporting layer **13** may be of a laminate structure having plural layers.

A first light emitting layer **14** is provided on the hole transporting layer **13** as a common layer covering substantially whole area of the substrate **3**. Such a first light emitting layer **14** emits light whose wavelength is equal to or shorter than that of blue light. The blue light means an emission color used as blue light in a final product of a display device. The first light emitting layer **14** comprises a host material and a light emitting dopant. For example, 4,4'-bis[2-(N,N-diphenylamino) phenyl]vinyl] biphenyl (DPAVBi) as the blue light emitting dopant is mixed 2.5% by weight with AND (anthracene dinaphthyl).

The first light emitting layer **14** is provided by a vapor deposition method. The first light emitting layer **14** that emits light whose wavelength is shorter than that of blue light includes, for example, a simple AND or a combination of AND as a host material and BD-052X (manufactured by Idemitsu Kosan) as a dopant material (about 5% by weight). In both cases, emitted light is usually recognized as blue light.

A second light emitting layer **15** is provided on the first light emitting layer **14** for each of the organic electrolumi-

nescence devices **5** (**5r**, **5g**, and **5b**). That is, a red light emitting layer **15r** emitting red light is provided as the second light emitting layer **15** in the red light emitting device **5r**. A green light emitting layer **15g** emitting a green light is provided as the second light emitting layer **15** in the green light emitting device **5g**. A blue light emitting layer **15b** emitting a blue light is provided as the second light emitting layer **15** in the blue light emitting device **5b**.

The red light emitting layer **15r** comprises, for example, a mixture of a host material and a red light emitting material. The red light emitting material may be either fluorescent or phosphorescent. In this embodiment, the red light emitting layer **15r** includes AND and 2,6-bis [(4'-methoxydiphenylamino)styryl]-1,5-dicyano naphthalene (BSN) (30% by weight). The thickness of the red light emitting layer **15r** is about 30 nm.

The green light emitting layer **15g** comprises, for example, a mixture of a host material and a green light emitting material. The green light emitting material may be either fluorescent or phosphorescent. In this embodiment, the green light emitting layer **15g** includes AND and coumarin **6** (5% by weight). The thickness of the red light emitting layer **15g** is about 30 nm.

The blue light emitting layer **15b** comprises, for example, a mixture of a host material and a blue light emitting material. The blue light emitting material may be either fluorescent or phosphorescent. In this embodiment, the blue light emitting layer **15b** includes AND and 4,4'-bis[2-[4-(N,N-diphenylamino)phenyl]vinyl]biphenyl (DPAVBi) (2.5% by weight). The thickness of the red light emitting layer **15b** is about 30 nm.

The second light emitting layers **15** (**15r**, **15g**, and **15b**) are provided with good positional accuracy by a thermal transfer method.

The electron transporting layer **16** is provided as a common layer on the second light emitting layer **15** to cover substantially whole area of the substrate **3**. The electron transporting layer **16** including a general electron transporting material, for example 8-hydroxyquinoline aluminum (Alq3), is vapor deposited with thickness of about 20 nm.

The electron injecting layer **17** is provided as a common layer on the electron transporting layer **16** to cover substantially whole area of the substrate **3**. The electron injecting layer **17** including a general electron injecting material, for example LiF, is vapor deposited with thickness of about 0.3 nm (vapor deposition rate: 0.01 nm/sec).

The upper electrode **18** is disposed on the electron injecting layer **17**. The upper electrode **18** is provided as a common electrode. For example, MgAg is used as the upper electrode **18** and vapor deposited with thickness of 10 nm.

Then, a protective film **22** is provided on the upper electrode **18** to cover substantially whole area of the substrate **3**. The protective film **22** is provided to prevent moisture from reaching the organic layer **19** with sufficient thickness using a low water-absorption material or a low water-permeable material. Further, when the display device is a top emission type, the protective film **22** is made of a material with good light transmissivity.

The material used for the protective film **22** may be either insulating or conductive. When using the insulating material, inorganic amorphous material, for examples, amorphous silicon ( $\alpha$ -Si), amorphous silicon carbide ( $\alpha$ -SiC), amorphous silicon nitride ( $\alpha$ -Si<sub>1-x</sub>N<sub>x</sub>), amorphous carbon ( $\alpha$ -C), etc. are preferably used. Since such inorganic amorphous materials do not form grains, and makes a good protective film with low water permeability.

For example, the protective film **22** comprising amorphous silicon nitride is provided by a CVD method with thickness of 2 to 3  $\mu$ m.

Further, when the display device **1** is the active matrix type, the protective layer **22** may be formed with a conductive material such as ITO and IXO.

A protective substrate **24** is provided on the protective film **22** via a resin material for adhesion (not illustrated). As the resin material for adhesion, UV-ray curable resin is used for example. As the protective substrate **24**, a glass substrate is used for instance. When the display device **1** is a top light emission type, the resin material for adhesion and the protective substrate **24** are made of a light transmitting material.

Furthermore, a color filter is additionally provided in a display device **1**. For example, a color filter is disposed for each of the organic electroluminescence devices **5r**, **5g**, and **5b** on the side from which light is taken out.

Then, a method of manufacturing the display device **1** is to be described with reference to a cross sectional step chart in FIG. **2**.

At first, as shown in FIG. **2(1)**, a lower electrode **11** is provided on the substrate **3**. An auxiliary electrode (not illustrated) may be optionally provided at the same time. Then, an insulating film **20** is provided to cover the peripheral portions of the lower electrode **11**. Then, the hole injecting layer **12**, the hole transporting layer **13**, and the first light emitting layer **14** are provided successively to cover substantially whole area of the substrate **11** by a vapor deposition method. Each of the layers **12** to **14** is provided as a film without using a mask.

Then, as shown in FIG. **2(2)**, a transfer substrate **30r** is prepared. In the transfer substrate **30r**, a red light emitting layer **15r** is provided via a light absorption layer **33** to cover substantially whole area of the glass substrate **31**.

Then, the transfer substrate **30r** is disposed being opposed to the substrate **3** having the first light emitting layer **14**. In this case, the transfer substrate **30r** and the substrate **3** are disposed such that the red light emitting layer **15r** and the first light emitting layer **14** are opposed to each other. The substrate **3** and the transfer substrate **30r** may be disposed to contact with each other so that the first light emitting layer **14** on the substrate **3** and the red light emitting layer **15r** on the transfer substrate **30r** are in contact with each other.

Then, a laser light **lr** with a wavelength, for example, of 800 nm is irradiated from the side of the transfer substrate **30r**. In this case, the laser light **lr** is selectively irradiated spotwise to the region for the red light emitting device. The laser is absorbed by the light absorption layer **33** and the red light emitting layer **15r** is thermally transferred selectively on the first light emitting layer **14** on the substrate **3**.

Then, a green light emitting layer and a blue light emitting layer are provided by repeating the above steps of the thermal transfer.

That is, as shown in FIG. **2(3)**, a transfer substrate **30g** with a light absorption layer **33** and a green light emitting layer **15g** is prepared, and the green light emitting layer **15g** is thermally and selectively transferred on the first light emitting layer **14** on the substrate **3**.

Further, as shown in FIG. **2(4)**, a transfer substrate **30b** with a light absorption layer **33** and a blue light emitting layer **15b** is prepared, and a blue light emitting layer **15b** is thermally and selectively transferred on the first light emitting layer **14** on the substrate **3**.

Each of the thermal transfer steps described with reference to FIG. **2(2)** to FIG. **2(4)** may be conducted in an optional order for the light emitting layers (**15r**, **15g**, and **15b**).

Further, the thermal transfer steps is preferably conducted in vacuum while they can also be conducted in an atmo-

spheric air. By conducting in vacuum, transfer is possible with lower energy of laser and thermal damages given to the light emitting layer to be transferred can be mitigated. Further, by conducting the thermal transfer step in vacuum, both substrates can be closely attached and the patterning accuracy is improved. In addition, by conducting all of the processes continuously in vacuum, degradation of the device can be prevented.

After forming the second light emitting layers **15r**, **15g** and **15b**, the electron transporting layer **16** and the electron injecting layer **17** are provided to cover substantially whole area of the substrate **3** by a vapor deposition method as shown in FIG. **1**. Then, the upper electrode **18** and a protective film **22** are formed by a film forming method, for example, a vapor deposition method or a CVD (chemical vapor deposition) method.

Each of the layers **16** to **22** is formed as a film without using a mask. Further, each of the layers **16** to **22** is preferably formed continuously in one identical film forming apparatus with no exposure to atmospheric air. This can prevent degradation of the organic layer **19** caused by moisture in atmospheric air.

When the auxiliary electrode is provided, the organic layers formed as a film on the lower electrode **11** may be partially removed by a laser abrasion method or the like before forming the upper electrode **18**. This connects the upper electrode **18** directly to the lower electrode **11** to improve the state of contact.

Finally, a protective substrate **24** is provided to complete a display device **1**.

According to the first embodiment, there is provided a light emitting layer provided by the vapor deposition method, that is, a first light emitting layer **14** being free of damages by thermal transfer and having high re-combination probability between electrons and holes.

Then, in the organic electroluminescence devices **5** (**5r**, **5g**, and **5b**), the second light emitting layers **15r**, **15g**, and **15b** are further provided. In the red light emitting device **5r** and the green light emitting device **5g** having the red light emitting layer **15r** or the green light emitting layer **15g** that emit light whose wavelength is longer than that of a first light emitting layer **14**, the re-combination energy of the first light emitting layer **14** rapidly moves to the second light emitting layer **15r** or **15g** and contributes to the emission of the red light or the green light.

On the other hand, in the blue light emitting device **5b** having the blue light emitting layer **15b** and the first light emitting layer **14**, since the first light emitting layer **14** formed by vapor deposition mainly acts as an emitting layer, the light emission efficiency and the luminance life are maintained at high levels. Also in case the first light emitting layer **14** emits light whose wavelength is shorter than that of blue light, light is emitted according to the same principle for the red light emitting device **5r** and the green light emitting device **5g** described above. That is, the re-combination energy at good efficiency generated in the first light emitting layer **14** rapidly moves to the blue light emitting layer **15b** to emit blue light.

The second light emitting layers **15r**, **15g**, and **15b** are provided by thermal transfer. Accordingly, the light emitting layer of each of the organic electroluminescence devices **5r**, **5g**, and **5b** is formed with good positional accuracy.

As the result, the pattern formation is possible with good positional accuracy, and the blue light emitting device **5b** is obtained with increased life and high light emission efficiency.

## Second Embodiment

FIG. **3** is a cross sectional view for a main portion of a display device as a second embodiment according to the invention. A display device **1'** in FIG. **3** is different from the display device **1** in FIG. **1** in that a blue light emitting device **5b'** has no second light emitting layer.

That is, a light emitting layer of a blue light emitting device **5b'** has only the first light emitting layer **14**. In the display device **1**, the first light emitting layer **14** emits light whose wavelength is equal to or shorter than that of blue light. In the display device **1'**, the first light emitting layer **14** emits blue light.

Also in this embodiment, the first light emitting layer **14** formed by vapor deposition emits blue light efficiently. Therefore, the same effect as the first embodiment can be obtained.

In addition, according to the second embodiment, since thermal transfer steps are necessary only twice, the manufacturing process can be simplified.

This invention is applicable to the embodiments in which the lower electrode **11** is used as the cathode and the upper electrode **18** is used as the anode.

This invention is also applicable to the embodiments in which the first light emitting layer is laminated on the second light emitting layer.

Furthermore, this invention is applicable to the embodiments in which the second light emitting layer is formed by other than thermal transfer, so long as the pattern can be formed with good accuracy.

Furthermore, this invention is applicable to a tandem organic EL device including plural units of organic layers each having a light emitting layer (light emitting units).

## EXAMPLE

Specific examples of the invention and comparative examples are shown below.

### Example 1

A red light emitting organic electroluminescence device **15r** was prepared (refer to FIG. **1**).

- (1) At first, above a glass substrate as a device forming substrate, an APC (Ag—Pd—Cu) layer as a silver alloy layer (film thickness: 120 nm), and an ITO film as a transparent conductive layer (film thickness: 10 nm) were formed in this order to form a lower electrode **11** of a two-layered structure. Then, an insulating film **20** of silicon oxide was formed to a thickness of about 2 μm by a sputtering method in a state of covering the circumferential edge of the lower electrode **11**. Then, the lower electrode **11** was exposed by lithography, on which m-MTDATA was vapor deposited at a film thickness of 25 nm as the hole injecting layer **12**, and α-NPD was vapor deposited to a film thickness of 30 nm as the hole transporting layer **13**.
- (2) As the first light emitting layer **14**, a host material AND mixed with 2.5% by weight of DPAVBi as a dopant material was vapor deposited to a film thickness of 5 nm.
- (3) On the other hand, a transfer substrate was prepared. At first, a light absorption layer comprising chromium with thickness of 200 nm was formed on a glass substrate by a

usual sputtering method. On the light absorption layer, AND as the host material mixed with 30% by weight of 2,6-bis[(4'-methoxydiphenylamino)styryl]-1,5-dicyano naphthalene (BSN) as a dopant material was formed to a film thickness of about 30 nm.

(4) Then, in the state where the formed films of organic layers are opposed to each other, the transfer substrate prepared in (3) was placed above the device preparing substrate **3** and adhered closely in vacuum. Both of the substrates were kept at a small distance of about 2  $\mu\text{m}$  by the thickness of the insulating film **20**. In this state, by irradiating a laser light at a wavelength of 800 nm from the back of the transfer substrate in an arrangement opposing to the red light pixel region of the device forming substrate **3**, the red light emitting layer **15r** was thermally transferred from the transfer substrate. The spot size for the laser light was controlled to 300  $\mu\text{m} \times 10 \mu\text{m}$ . The laser light was scanned in the direction perpendicular to the longitudinal size of the light. The energy density was at 2.6 E-3  $\text{mJ}/\mu\text{m}^2$ .

(5) As the electron transporting layer **16**, 8-hydroxyquinoline aluminum (Alq3) was vapor deposited to a film thickness of about 20 nm. Successively, as the electron injecting layer **17**, LiF was vapor deposited to a film thickness of about 0.3 nm (vapor deposition rate: 0.01 nm/sec). Then, as the upper electrode **18**, Mg:Ag was vapor deposit to a film thickness of 10 nm.

#### Example 2

A green light emitting organic electroluminescence device **15g** was prepared.

The same procedures as those in Example 1(1), (2) were conducted.

In Example 1(3), AND as the host material mixed with 5% by weight of coumarin **6** was formed as a green emitting layer instead of the red light emitting layer to a film thickness of about 30 nm.

Then, the same procedures as those in Example 1(4), (5) were conducted by using the transfer substrate prepared as described above.

#### Example 3

A blue light emitting organic electroluminescence device **15b** was prepared.

The same procedures as those in Example 1(1), (2) were conducted.

In Example 1(3), AND as the host material mixed with 2.5% by weight of DPAVBi as the dopant material was formed to a thickness of about 30 nm as the blue light emitting layer instead of the red light emitting layer.

Then, the same procedures as those in Example 1(4), (5) were conducted by using the transfer substrate prepared as described above.

#### Example 4

A blue light emitting organic electroluminescence device **15b'** was prepared.

In this case, only the procedures (1), (2), and (5) in Example 1 were conducted to prepare a blue light emitting device **15b'** in which the light emitting layer was constructed only with the blue light emitting first light emitting layer **14** (refer to FIG. 3).

#### Comparative Example 1

The procedures in Example 1, procedures (1), (3), (4) and (5) were conducted successively while saving the procedure

(2) to prepare an organic electroluminescence device in which the light emitting layer was constructed only with the red light emitting layer **15r** without disposing the first light emitting layer **14**.

#### Comparative Example 2

The procedures in Example 2, procedures (1), (3), (4) and (5) were conducted successively while saving the procedure (2) to prepare an organic electroluminescence device in which the light emitting layer was constructed only with the green light emitting layer **15g** without disposing the first light emitting layer **14**.

#### Comparative Example 3

In the procedures in Example 3, procedures (1), (3), (4) and (5) were conducted successively while saving the procedure (2) to prepare an organic electroluminescence device in which the light emitting layer was constructed only with the blue light emitting layer **15b** without disposing the first light emitting layer **14**.

#### Result of Evaluation

For the organic electroluminescence devices prepared as described above, in a state of applying a constant current at a density of 10  $\text{mA}/\text{cm}^2$ , the light emission efficiency and the chromaticity were measured by using a spectral radiance meter. Further, a life test was conducted in a state of setting the current application such that devices using the identical dopant emitted light at an identical luminance and the rate of decrease in the relative luminance after lapse of 100 hrs was measured. The results are shown in the following Table 1.

TABLE 1

Device constitution	CIE chromaticity (x, y)	Light emission efficiency [cd/A]	Rate of decrease in luminance (%)
Example 1 Red light emitting device 5r	(0.64, 0.32)	5.3	15
(Comp. Example 1) Red light emitting device	(0.63, 0.32)	5.5	17
Example 2 Green light emitting device 5g	(0.22, 0.68)	13	15
(Comp. Example 2) Green light emitting device	(0.22, 0.66)	15	14
Example 3 Blue light emitting device 5b	(0.16, 0.21)	6.2	11
(Comp. Example 3) Blue light emitting device	(0.16, 0.20)	3.6	46
Example 4 Blue light emitting device 5b'	(0.16, 0.21)	3.3	25

(Comparative Example): with no first light emitting layer

When comparing the result of evaluation between Example 1 and Comparative Example 1, it was confirmed that the chromaticity and the light emission efficiency were obtained about at the same extent and the rate of decrease in the luminance was also suppressed by about the same extent also for the red light emitting device **5r** of Example 1 provided with the blue light emitting first emitting layer, as those for the red light emitting device of Comparative Example 1 not provided with the first light emitting layer. This was identical also in the comparison between the green light emitting devices of Example 2 and Comparative Example 2.

This is considered to be attributable to that the light was scarcely emitted in the first light emitting layer **14** since the

light emission from the first light emitting layer **14** disposed in Examples 1, 2 was at a short wavelength of high energy and the re-combination energy in the first light emitting layer **14** conducted rapidly to the red light emitting layer **15r** and the green light emitting layer **15g**.

On the other hand, when comparing the result of evaluation between Example 3 and Comparative Example 3, it was confirmed that the light emission efficiency increased twice or more and also the rate of decrease in the luminance was suppressed to ¼ or less for the blue light emitting device **5b** of Example 3 provided with the blue light emitting first light emitting layer compared with the blue light emitting device of Comparative Example 3 not provided with the first light emitting layer. Further, degradation of the chromaticity was not observed as well.

In view of the result described above, it was confirmed that the characteristics of the blue light emitting device **5g** could be improved while maintaining the characteristics of the red light emitting device **5r** and the green light emitting **5b** in the display devices in which the organic electroluminescence devices **5r**, **5g** and **5b** for each of the colors in Examples 1 to 3. This enables to favorably maintain the characteristics of the organic electroluminescence devices **5r**, **5g**, and **5b** emitting for each of the colors in full color display devices using the organic electroluminescence devices by forming the second light emitting layers **15r**, **15g**, and **15b** by the thermal transfer.

Further, when comparing the result of evaluation between Example 4 and Comparative Example 3, it was confirmed that the rate of decrease in the luminance was suppressed to about ½ in the blue light emitting device **5b'** of Example 3 in which the light emitting layer was constructed only with the blue light emitting first light emitting layer, compared with the blue light emitting device of Comparative Example 3 not provided with the first light emitting layer. Further, degradation of the chromaticity was not observed and it was confirmed that lowering of the light emission efficiency could also be restricted.

Accordingly, it was confirmed that the life of the blue light emitting device **5b'** could be increased by constructing the light emitting layer only with the first light emitting layer formed by vapor deposition.

It should be understood by those skilled in the art that various modifications, combinations, sub-combinations and alterations may occur depending on design requirements and other factors insofar as they are within the scope of the appended claims or the equivalents thereof.

What is claimed is:

1. A display device having:

a plurality of organic electroluminescence devices arranged on a substrate, each of the organic electroluminescence devices including a lower electrode, an organic layer containing at least one light emitting layer, and an upper electrode in this order,

wherein

at least three of said organic electroluminescence devices, each of which emits a different color, have a common first light emitting layer,

at least one of said at least three organic electroluminescence devices has a second light emitting layer which is stacked above said first light emitting layer,

the first light emitting layer emits light with a wavelength that is equal to or shorter than that of blue light, the at least three of said organic electroluminescence devices have in common, distinctly from the first light emitting layer, a hole injecting layer, a hole transporting layer, an electron injecting layer and an electron transporting layer,

the hole injecting and transport layers are located below the first light emitting layer and the second light emitting layer, and

the electron injecting and transport layers are located above the first light emitting layer and the second light emitting layer.

2. The display device according to claim 1, wherein the second light emitting layer emits light whose wavelength is equal to or longer than that of blue light.

3. The display device according to claim 1, wherein the organic electroluminescence devices emit red light, green light, or blue light respectively.

4. The display device according to claim 3, wherein:

the red light emitting organic electroluminescence device includes a red light emitting layer that emits a red light as the second light emitting layer and the first light emitting layer,

the green light emitting organic electroluminescence device includes a green light emitting layer that emits a green light as the second light emitting layer and the first light emitting layer, and

the blue light emitting organic electroluminescence device includes only the first light emitting layer.

5. The display device according to claim 3, wherein:

the red light emitting organic electroluminescence device includes a red light emitting layer that emits a red light as the second light emitting layer and the first light emitting layer,

the green light emitting organic electroluminescence device includes a green light emitting layer that emits a green light as the second light emitting layer and the first light emitting layer, and

the blue light emitting organic electroluminescence device includes a blue light emitting layer that emits a blue light as the second light emitting layer and the first light emitting layer.

6. The display device according to claim 4, wherein the first light emitting layer is provided by a vapor deposition process and the second light emitting layer is provided by a thermal transfer process.

7. The display device according to claim 5, wherein the first light emitting layer is provided by a vapor deposition process and the second light emitting layer is provided by a thermal transfer process.

8. A method of manufacturing a display device having a plurality of organic electroluminescence devices arranged on a substrate, each of the organic electroluminescence devices includes a lower electrode, an organic layer containing at least one light emitting layer, and an upper electrode in this order, comprising:

forming a lower electrode over a substrate;

forming a hole injecting layer and a hole transporting layer on the electrode;

forming, via a vapor deposition process, a first light emitting layer that emits light with a wavelength that is equal to or shorter than that of blue light so that at least three of said organic electroluminescence devices, each of which emits a different color, have said first light emitting layer in common;

forming, via a thermal transfer process, a second light emitting layer that emits light with a wavelength that is equal to or longer than that of blue light so that at least one but not all of said three organic electroluminescence devices has a light emitting layer with a laminated structure of said first light emitting layer and the second light

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emitting layer, said second light emitting layer being positioned above said common first light emitting layer; and  
forming an electron injecting layer and an electron transporting layer across the plurality of organic electroluminescence devices. 5  
**9.** A display device comprising:  
a substrate; and  
at least three organic electroluminescent devices in said substrate, 10  
wherein,  
said organic electroluminescence devices, each of which emits a different color, share in common at least one organic electroluminescent light emitting layer, a hole injecting layer, a hole transporting layer, an electron injecting layer and an electron transporting layer, 15  
two of said organic electroluminescence device also include respective, unique, organic electroluminescence light emitting layers,  
said unique organic electroluminescence light emitting layers are located above said common organic electroluminescent light emitting layer, 20  
said two organic electroluminescence devices emit at least one of red and green light,

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one of said organic electroluminescence devices other than said two of said organic electroluminescence devices emits blue light,  
the hole injecting and transport layers formed below the common organic electroluminescent light emitting layer and said unique organic electroluminescence light emitting layers, and  
the electron injecting and transport layers are located above the common organic electroluminescent light emitting layer and said unique organic electroluminescence light emitting layers.  
**10.** The display device according to claim 1, wherein the common first light emitting layer is in contact with and substantially covers an entire surface of the hole injecting and transport layer.  
**11.** The method according to claim 8, wherein the common first light emitting layer is in contact with and substantially covers an entire surface of the hole injecting and transport layer.  
**12.** The display device according to claim 9, wherein the common first light emitting layer is in contact with and substantially covers an entire surface of the hole injecting and transport layer.

\* \* \* \* \*

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摘要(译)

在具有布置在基板上的多个有机电致发光器件的显示装置中，每个器件包括下电极，至少包含发光层的有机层和上电极，at的发光层至少一些有机电致发光器件具有通过气相沉积形成的第一发光层和通过热转移形成的第二发光层，并且第一发光层发射波长等于或短于蓝光的光。

